

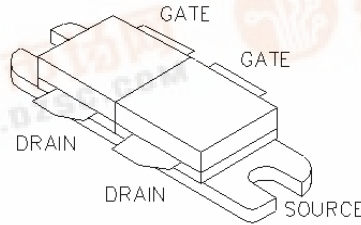


F1072

General Description

Silicon VDMOS and LDMOS transistors designed specifically for broadband RF applications. Suitable for Military Radios, Cellular and Paging Amplifier Base Stations, Broadcast FM/AM, MRI, Laser Driver and others.

"Polyfet"TM process features gold metal for greatly extended lifetime. Low output capacitance and high F_t enhance broadband performance



PATENTED GOLD METALIZED SILICON GATE ENHANCEMENT MODE RF POWER VDMOS TRANSISTOR

100Watts Gemini

Package Style AH

HIGH EFFICIENCY, LINEAR, HIGH GAIN, LOW NOISE

ABSOLUTE MAXIMUM RATINGS (TC = 25 °C)

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	DC Drain Current	Drain to Gate Voltage	Drain to Source Voltage	Gate to Source Voltage
290 Watts	0.6 °C/W	200 °C	-65 °C to 150 °C	12 A	70 V	70V	30V

RF CHARACTERISTICS (100WATTS OUTPUT)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	10			dB	$I_{dq} = 1.2 A, V_{ds} = 28.0 V, F = 400 MHz$
η	Drain Efficiency		60		%	$I_{dq} = 1.2 A, V_{ds} = 28.0 V, F = 400 MHz$
VSWR	Load Mismatch Toleranc			20:1	Relative	$I_{dq} = 1.2 A, V_{ds} = 28.0 V, F = 400 MHz$

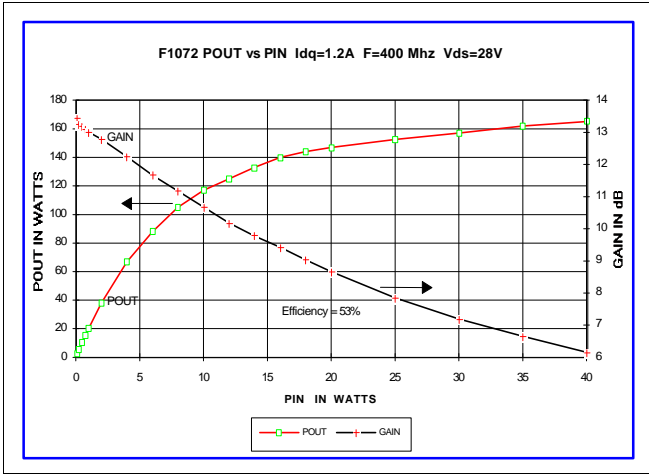
ELECTRICAL CHARACTERISTICS (EACH SIDE)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltag	65			V	$I_{ds} = 0.15 A, V_{gs} = 0V$
Idss	Zero Bias Drain Curren			3	mA	$V_{ds} = 28.0 V, V_{gs} = 0V$
Igss	Gate Leakage Curren			1	uA	$V_{ds} = 0 V, V_{gs} = 30V$
Vgs	Gate Bias for Drain Curren	1		7	V	$I_{ds} = 0.3 A, V_{gs} = V_{ds}$
gM	Forward Transconductanc		2.4		Mho	$V_{ds} = 10V, V_{gs} = 5V$
Rdson	Saturation Resistanc		0.5		Ohm	$V_{gs} = 20V, I_{ds} = 12A$
Idsat	Saturation Curren		16.5		Amp	$V_{gs} = 20V, V_{ds} = 10V$
Ciss	Common Source Input Capacitanc		99		pF	$V_{ds} = 28.0 V, V_{gs} = 0V, F = 1 MHz$
Crss	Common Source Feedback Capacitanc		12		pF	$V_{ds} = 28.0 V, V_{gs} = 0V, F = 1 MHz$
Coss	Common Source Output Capacitanc		60		pF	$V_{ds} = 28.0 V, V_{gs} = 0V, F = 1 MHz$

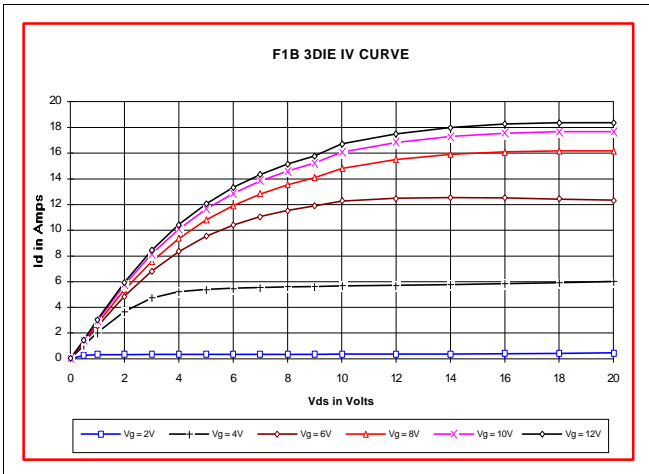


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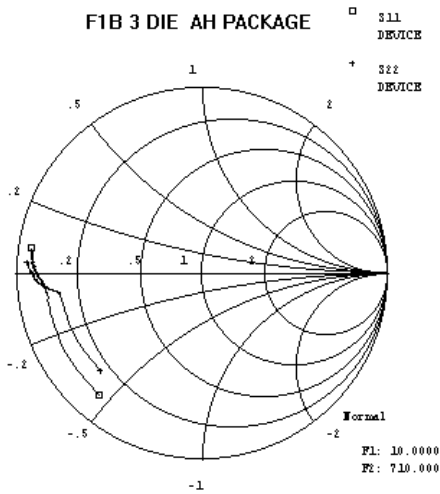
POUT VS PIN GRAPH



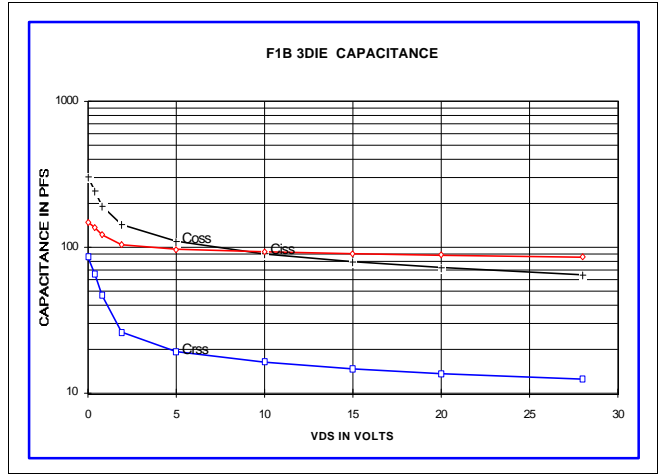
IV CURVE



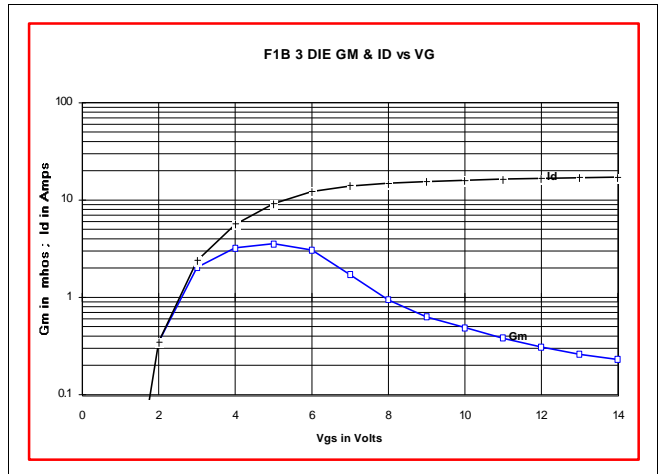
S11 AND S22 SMITH CHART



CAPACITANCE VS VOLTAGE



ID AND GM VS VGS



PACKAGE DIMENSIONS IN INCHES

